Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

Except below description page
 "Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

MOS FET

FC8J33040L

Panasonic

FC8J33040L

Dual N-channel MOSFET

For switching For DC-DC Converter

■ Features

- Low drain-source On-state Resistance : RDS(on) typ = 48 m Ω (VGS = 4.5 V)
- High-speed switching : Qg = 2.8 nC
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 7A
- Basic Part Number: Dual Nch MOS 33V (Individual)

■ Packaging

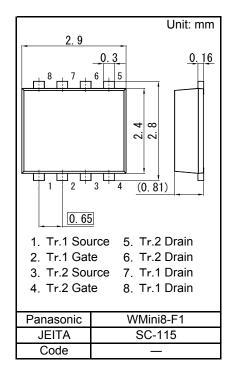
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

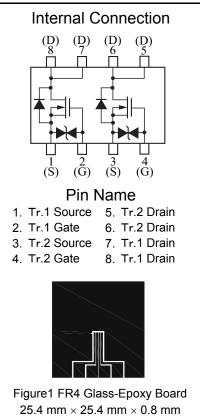
Absolute Maximum Ratings Ta = 25 °C Tr.1, Tr.2

Parameter	Symbol	Rating	Unit			
Drain-source Voltage	VDS	33	V			
Gate-source Voltage	VGS	±20	V			
Drain Current (Steady State) *1	ID	5				
Drain Current (t = 10 s) *1	טו	5.5				
Drain Current (Pulsed) *1,*2	IDp	20	Α			
Source Current (Pulsed)	ISp	5				
(Body Diode) *1,*2	(BD)	5	<u> </u>			
Total Power Dissipation (Steady State) *1	PD	1	W			
Total Power Dissipation (t = 10 s) *1	וו	1.3	VV			
Channel Temperature	Tch	150	°C			
Operating Ambient Temperature	Topr	-40 to + 85	°C			
Storage Temperature Range	Tstg	-55 to +150	°C			
11 (1) 11 11 11 11 11 11 11 11						

Note) *1 Device mounted on a glass-epoxy board (See Figure 1)

*2 Pulse test: Ensure that the channel temperature does not exceed 150°C.





Doc No. TT4-EA-13030

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MOS FET

FC8J33040L

■ Electrical Characteristics Ta = 25° C $\pm 3^{\circ}$ C Tr.1, Tr.2

Static Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1 mA, VGS = 0 V	33			V
Zero Gate Voltage Drain Current	IDSS	VDS = 33 V, VGS = 0 V			1	μΑ
Gate-source Leakage Current	IGSS	VGS = ±16 V, VDS = 0 V			±10	μΑ
Gate-source Threshold Voltage	Vth	ID = 0.26 mA, VDS = 10 V	1		2.5	V
		ID = 2.5 A, VGS = 10 V		32	38	mΩ
	RDS(on)2	ID = 2.5 A, VGS = 4.5 V		48	68	

Dynamic Characteristics
Input Capacitance

Coss	VDS - 10 V, VGS - 0 V	4.0	
	VDS = 10 V, VGS = 0 V f = 1 MHz	40	pF
Crss	1 - 1 1011 12	35	
td(on)	VDD = 15 V, VGS = 0 to 10 V	7	
tr	ID = 2.5 A	3	ns
td(off)	VDD = 15 V, VGS = 10 to 0 V	15	113
tf	ID = 2.5 A	9	
Qg	VDD = 15 V VGS = 0 to 4.5 V	2.8	
Qgs	-	1.1	nC
Qgd	10-37	1.2	
	td(on) tr td(off) tf Qg Qgs	td(on) VDD = 15 V, VGS = 0 to 10 V tr ID = 2.5 A td(off) VDD = 15 V, VGS = 10 to 0 V tf ID = 2.5 A Qg VDD = 15 V, VGS = 0 to 4.5 V, ID = 5 A	td(on) VDD = 15 V, VGS = 0 to 10 V 7 tr ID = 2.5 A 3 td(off) VDD = 15 V, VGS = 10 to 0 V 15 tf ID = 2.5 A 9 Qg VDD = 15 V, VGS = 0 to 4.5 V, 1.1

Body Diode Characteristic

Diode Forward Voltage *1	VSD	IS = 2.5 A, VGS = 0 V	8.0	1.2	V

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

Established: 2011-01-13 Revised: 2013-07-31

^{2. *1} Pulse test: Ensure that the channel temperature does not exceed 150°C.

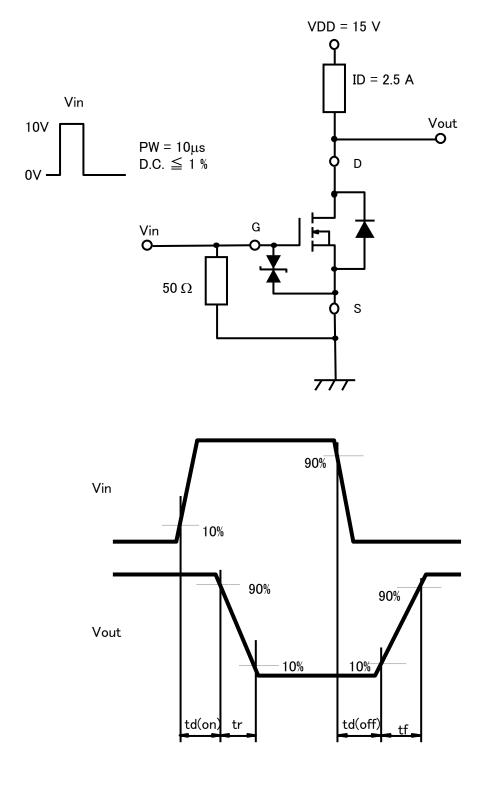
^{*2} Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

MOS FET

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*2 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

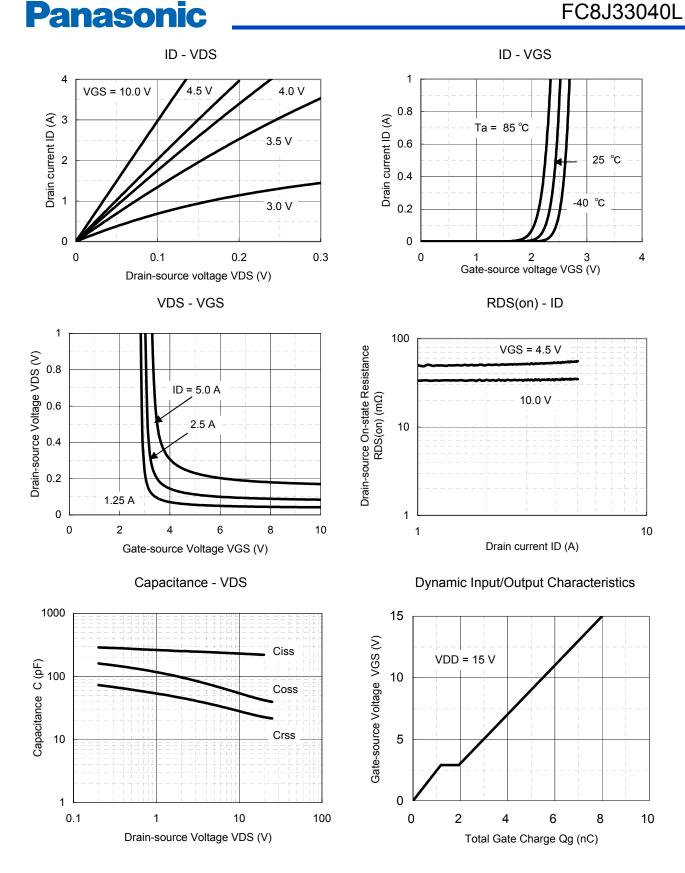


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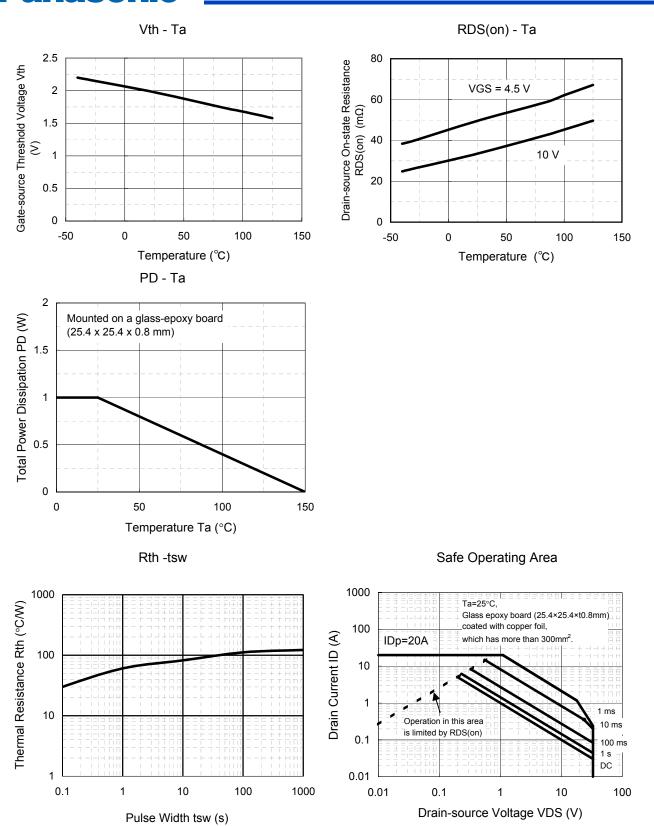
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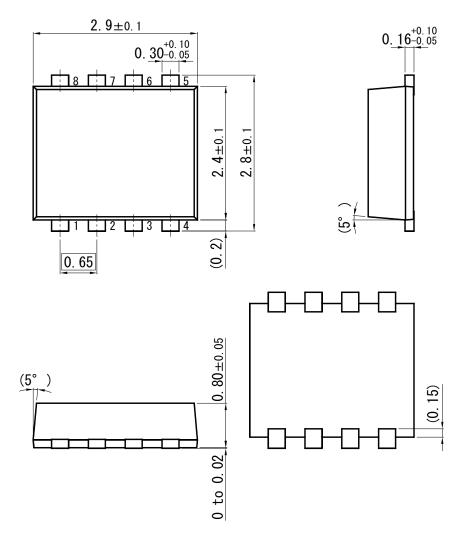
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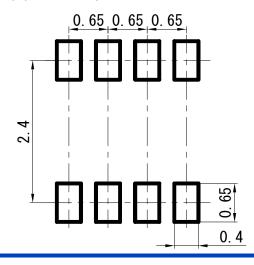
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WMini8-F1

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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